

**X0202/A/B****SCR****SENSITIVE SCRS****DESCRIPTION**

The UTC **X0202/A/B** SCR series is suitable for all applications where the available gate current is limited, such as ground fault circuit interruptors, overvoltage crowbar protection in low power supplies, capacitive ignition circuit,

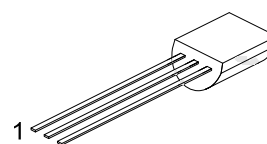
FEATURES

* $I_{T(RMS)}$: 1.25A

* V_{DRM}/V_{RRM} : 600/800/1000V



SOT-223



TO-92

ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
X0202L-AA3-R	X0202G-AA3-R	SOT-223	K	A	G	Tape Reel
X0202L-T92-B	X0202G-T92-B	TO-92	K	G	A	Tape Box
X0202L-T92-K	X0202G-T92-K	TO-92	K	G	A	Bulk
X0202L-T92-R	X0202G-T92-R	TO-92	K	G	A	Tape Reel
X0202xL-AA3-R	X0202xG-AA3-R	SOT-223	K	A	G	Tape Reel
X0202xL-T92-B	X0202xG-T92-B	TO-92	K	G	A	Tape Box
X0202xL-T92-K	X0202xG-T92-K	TO-92	K	G	A	Bulk
X0202xL-T92-R	X0202xG-T92-R	TO-92	K	G	A	Tape Reel

Note: Pin Assignment: G: Gate A: Anode K: Cathode

X0202xL-AA3-R	
(1) Packing Type	(1) B: Tape Box, K: Bulk, R: Tape Reel
(2) Package Type	(2) AA3: SOT-223, T92: TO-92
(3) Lead Free	(3) L: Lead Free, G: Halogen Free
(4) V_{DRM} , V_{RRM}	(4) Blank: 600V, A: 800V, B: 1000V

■ **ABSOLUTE MAXIMUM RATINGS** (unless otherwise specified)

PARAMETERS		SYMBOL	RATINGS	UNIT
Peak Repetitive Forward and Reverse Blocking Voltage ($T_J=110^{\circ}\text{C}$, $R_{GK}=1\text{k}\Omega$)	X0202	V_{DRM} , V_{RRM}	600	V
	X0202A		800	V
	X0202B		1000	V
RMS On-State Current 180°C Conduction Angle	$T_{\text{tab}}=95^{\circ}\text{C}$	$I_{\text{T(RMS)}}$	1.25	A
Average On-State Current 180°C Conduction Angle	$T_{\text{tab}}=95^{\circ}\text{C}$	$I_{\text{T(AV)}}$	0.8	A
Non Repetitive Surge Peak on-State Current ($t_p=8.3\text{ms}$ $T_J=25^{\circ}\text{C}$)		I_{TSM}	25	A
Non Repetitive Surge Peak on-State Current ($t_p=10\text{ms}$ $T_J=25^{\circ}\text{C}$)		I_{TSM}	22.5	A
I^2t Value for Fusing ($t_p=10\text{ms}$ $T_J=25^{\circ}\text{C}$)		I^2t	2.5	A^2S
Critical Rate Of Rise Of On-state Current $I_G=2 \times I_{GT}$, $t_r \leq 100\text{ns}$, $f=60\text{Hz}$, $T_J=125^{\circ}\text{C}$		di/dt	50	$\text{A}/\mu\text{s}$
Peak Gate Current ($p=20\mu\text{s}$ $T_J=125^{\circ}\text{C}$)		I_{GM}	1.2	A
Average Gate Power Dissipation ($T_J=125^{\circ}\text{C}$)		$P_{G(AV)}$	0.2	W
Operating Junction Temperature Range		T_J	$-40 \sim +125$	$^{\circ}\text{C}$
Storage Junction Temperature Range		T_{STG}	$-40 \sim +150$	$^{\circ}\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **THERMAL DATA**

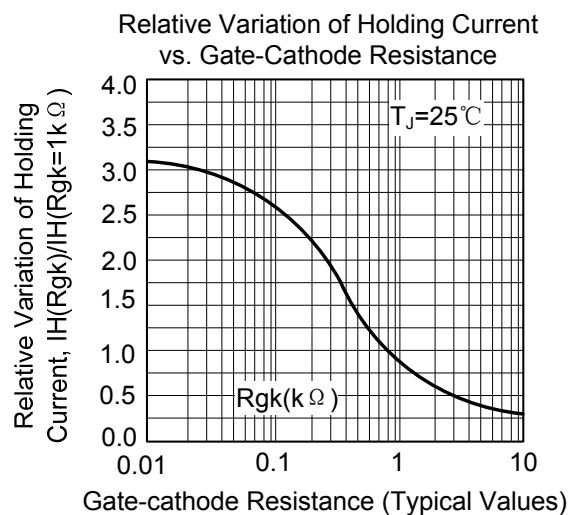
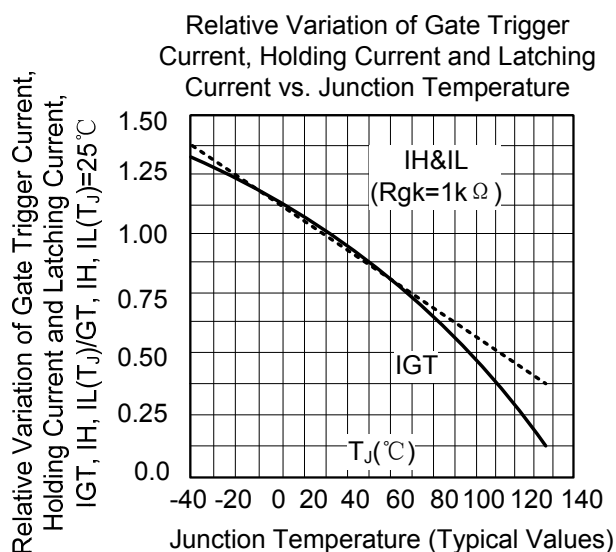
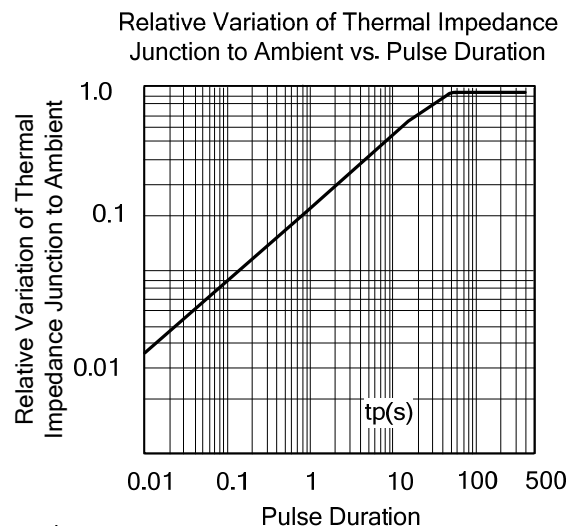
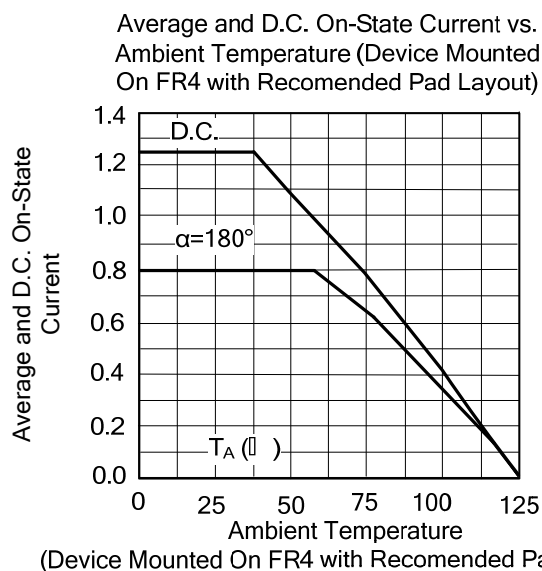
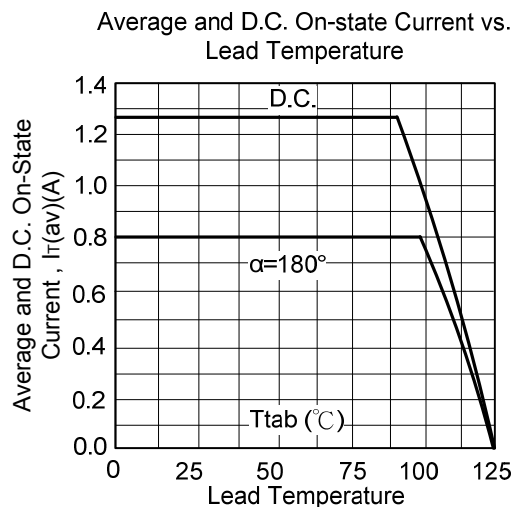
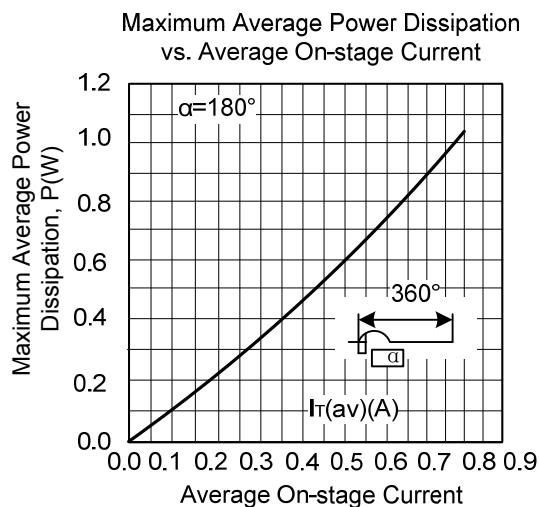
PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Tab	SOT-223	θ_{JT}	25	$^{\circ}\text{C}/\text{W}$
	TO-92		60	$^{\circ}\text{C}/\text{W}$
Junction to Ambient ($S=5\text{cm}$)	SOT-223	θ_{JA}	60	$^{\circ}\text{C}/\text{W}$
	TO-92		150	$^{\circ}\text{C}/\text{W}$

S=Copper surface under tab

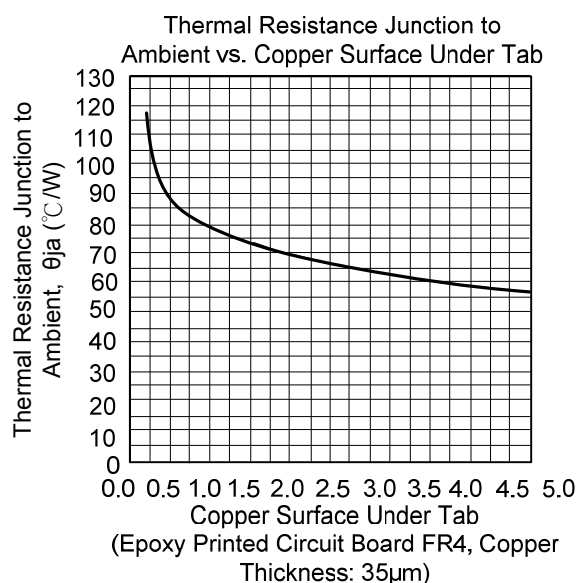
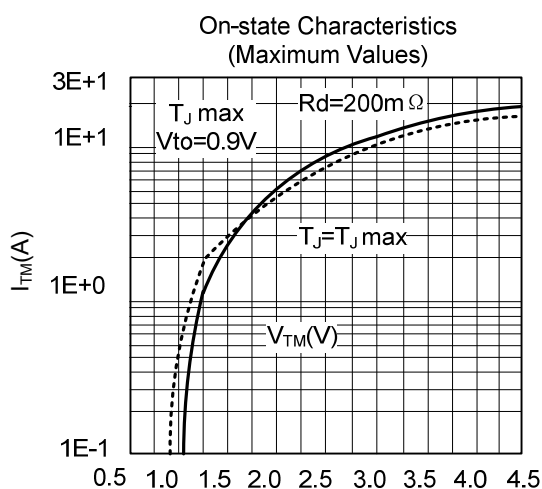
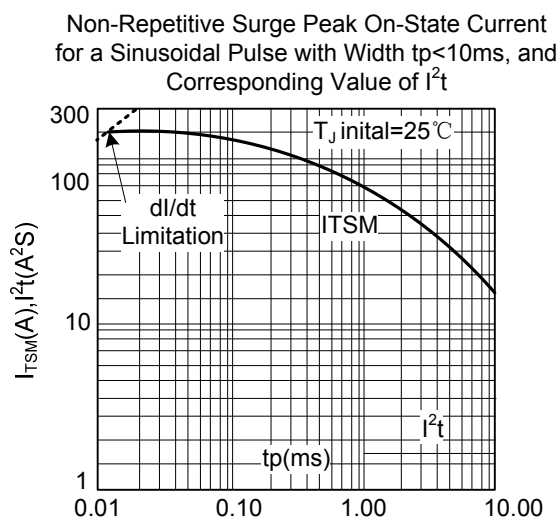
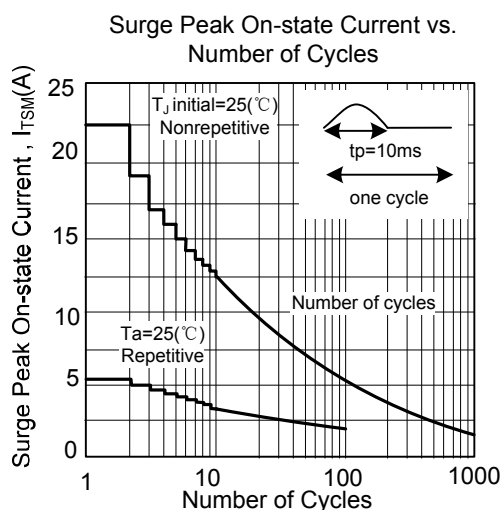
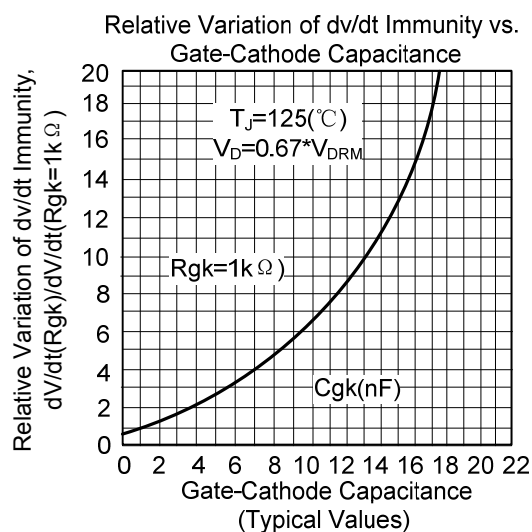
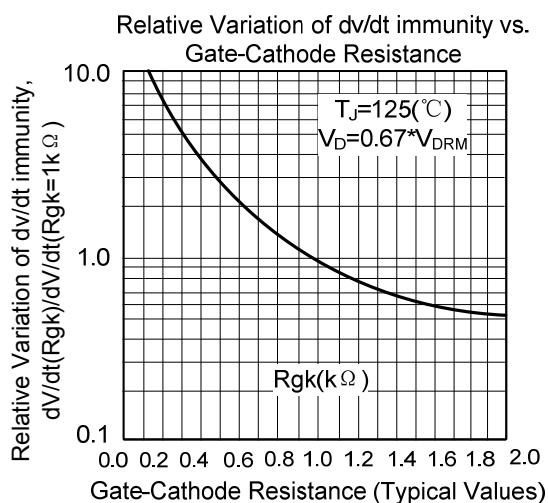
■ **ELECTRICAL CHARACTERISTI**

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Peak Forward or Reverse Blocking Current	$T_J=25^{\circ}\text{C}$	I_{DRM} , I_{RRM}	$V_{\text{DRM}}=V_{\text{RRM}}$, $R_{GK}=1\text{k}\Omega$			5	μA
	$T_J=125^{\circ}\text{C}$					500	μA
Peak Forward On-State Voltage		V_{TM}	$I_{\text{TM}}=2.5\text{A}$, $t_p=380\mu\text{s}$			1.45	V
Gate Trigger Current		I_{GT}	$V_D=12\text{V}$, $R_L=140\Omega$			200	μA
Gate Trigger Voltage		V_{GT}	$V_D=12\text{V}$, $R_L=140\Omega$			0.8	V
Gate Non-Trigger Voltage		V_{GD}	$V_D=V_{\text{DRM}}$, $R_L=3.3\text{k}\Omega$, $R_{GK}=1\text{k}\Omega$, ($T_J=125^{\circ}\text{C}$)	0.1			V
Holding Current		I_H	$I_T=50\text{mA}$, $R_{GK}=1\text{k}\Omega$			5	mA
Latch Current		I_L	$I_G=1\text{mA}$, $R_{GK}=1\text{k}\Omega$			6	mA
Critical Rate of Rise of Off-State Voltage		dv/dt	$V_D=67\%V_{\text{DRM}}$, $R_{GK}=1\text{k}\Omega$, ($T_J=110^{\circ}\text{C}$)	10			$\text{V}/\mu\text{s}$
Peak Reversed Gate Voltage		V_{RG}	$I_{RG}=10\mu\text{A}$	8			V
Threshold Voltage		V_{TO}	($T_J=125^{\circ}\text{C}$)			0.9	V
Dynamic Resistance		R_d	($T_J=125^{\circ}\text{C}$)			200	$\text{m}\Omega$

■ TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS(Cont.)



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